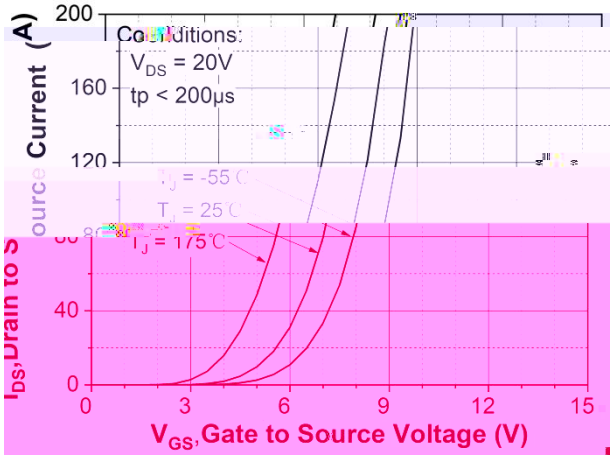
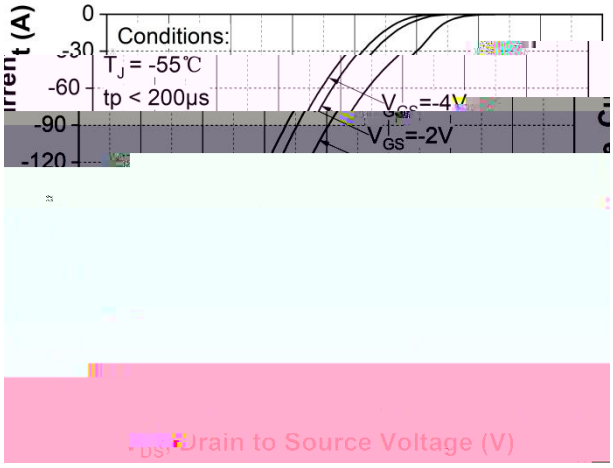
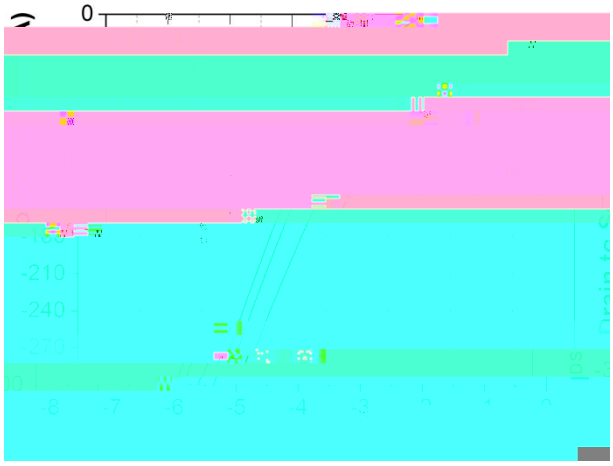
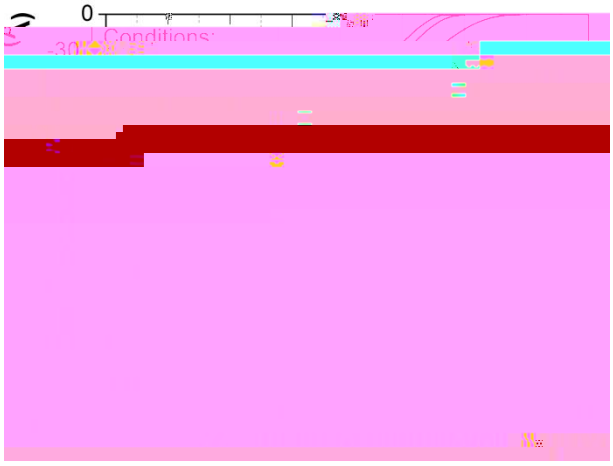
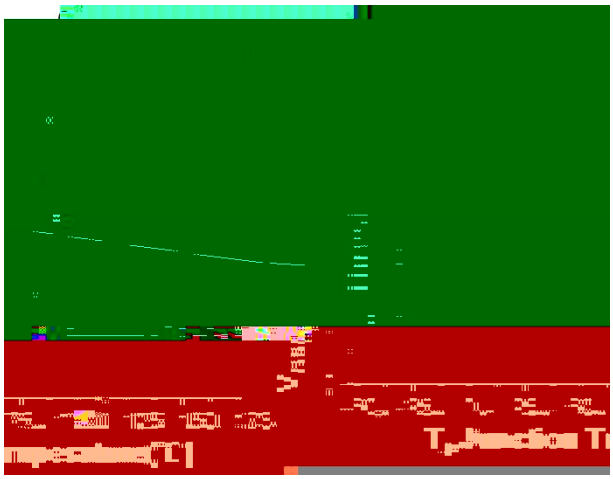
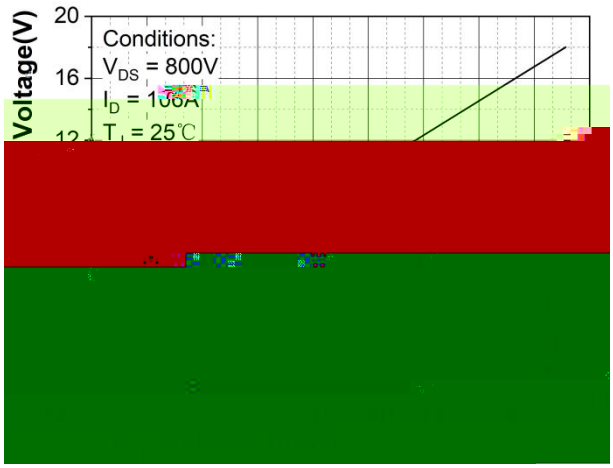

Conditions:
V_{DS} = 20V
tp < 200μs
T_J = -55℃
T_J = 25℃
T_J = 175℃
I_{DS},Drain to Source Current (A)
V_{GS},Gate to Source Voltage (V)


Conditions:
T_J = -55℃
tp < 200μs
V_{GS}=-4V
V_{GS}=-2V
Drain to Source Voltage (V)








Voltage(V)
Conditions:
V_{DS} = 800V
I_D = 100A
T_J = 25℃